# 74HC4094-Q100; 74HCT4094-Q100

8-stage shift-and-store bus register Rev. 4 — 21 March 2024

**Product data sheet** 

## 1. General description

The 74HC4094-Q100; 74HCT4094-Q100 is an 8-bit serial-in/serial or parallel-out shift register with a storage register and 3-state outputs. Both the shift and storage register have separate clocks. The device features a serial input (D) and two serial outputs (QS1 and QS2) to enable cascading. Data is shifted on the LOW-to-HIGH transitions of the CP input. Data is available at QS1 on the LOW-to-HIGH transitions of the CP input to allow cascading when clock edges are fast. The same data is available at QS2 on the next HIGH-to-LOW transition of the CP input to allow cascading when clock edges are slow. The data in the shift register is transferred to the storage register when the STR input is HIGH. Data in the storage register appears at the outputs whenever the output enable input (OE) is HIGH. A LOW on OE causes the outputs to assume a high-impedance OFF-state. Operation of the OE input does not affect the state of the registers. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V<sub>CC</sub>.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

## 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)

  Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Complies with JEDEC standard JESD7A
- Input levels:
  - For 74HC4094-Q100: CMOS level
  - For 74HCT4094-Q100: TTL level
- Low-power dissipation
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

## 3. Applications

- Serial-to-parallel data conversion
- Remote control holding register

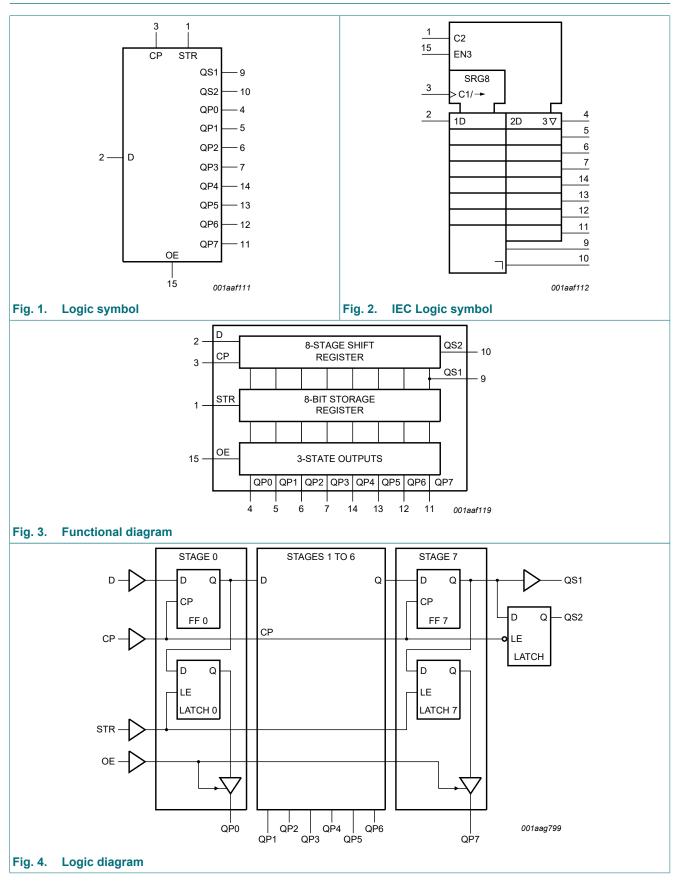
## 4. Ordering information

### Table 1. Ordering information

Type number	Package										
	Temperature range	Name	Description	Version							
74HC4094D-Q100 74HCT4094D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	<u>SOT109-1</u>							
74HC4094PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	<u>SOT403-1</u>							

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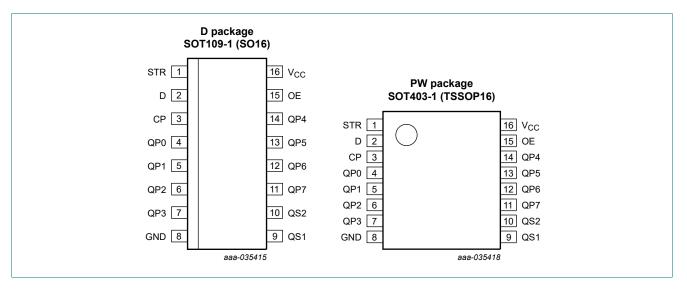
# 5. Functional diagram



74HC\_HCT4094\_Q100

# 6. Pinning information





## 6.2. Pin description

Table 2. Pin description									
Symbol	Pin	Description							
STR	1	strobe input							
D	2	data input							
СР	3	clock input							
QP0, QP1, QP2, QP3, QP4, QP5, QP6, QP7	4, 5, 6, 7, 14, 13, 12, 11	parallel output							
GND	8	ground supply voltage							
QS1, QS2	9, 10	serial output							
OE	15	output enable input							
V <sub>CC</sub>	16	supply voltage							

# 7. Functional description

## Table 3. Function table

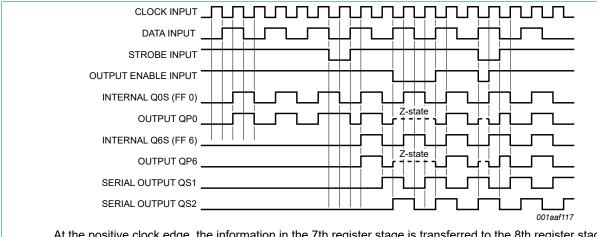
H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = HIGH-impedance OFF-state; NC = no change;

 $\uparrow$  = positive-going transition;  $\downarrow$  = negative-going transition;

Q6S = the data in register stage 6 before the LOW to HIGH clock transition;

Q7S = the data in register stage 7 before the HIGH to LOW clock transition.

Inputs				Parallel c	outputs	Serial out	tputs
СР	OE	OE STR D QP0 QPn					QS2
1	L	X	Х	Z	Z	Q6S	NC
$\downarrow$	L	X	Х	Z	Z	NC	Q7S
1	н	L	Х	NC	NC	Q6S	NC
1	Н	Н	L	L	QPn -1	Q6S	NC
↑	н	Н	Н	Н	QPn -1	Q6S	NC
$\downarrow$	Н	Н	Н	NC	NC	NC	Q7S



At the positive clock edge, the information in the 7th register stage is transferred to the 8th register stage and the QSn outputs.

## Fig. 5. Timing diagram

## 8. Limiting values

## Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Мах	Unit
V <sub>CC</sub>	supply voltage			-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V		-	±20	mA
I <sub>OK</sub>	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V		-	±20	mA
lo	output current	$V_{O} = -0.5 V \text{ to } (V_{CC} + 0.5 V)$		-	±25	mA
I <sub>CC</sub>	supply current			-	+50	mA
I <sub>GND</sub>	ground current			-	-50	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation		[1]	-	500	mW

 For SOT109-1 (SO16) package: P<sub>tot</sub> derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package: P<sub>tot</sub> derates linearly with 8.5 mW/K above 91 °C.

# 9. Recommended operating conditions

## Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74H	IC4094-C	100	74H	Unit		
			Min	Тур	Max	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V <sub>CC</sub> = 6.0 V	-	-	83	-	-	-	ns/V

# **10. Static characteristics**

## Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Мах	Min	Max	1
74HC40	94-Q100								-	
VIH	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V <sub>OH</sub>	HIGH-level	$V_{I} = V_{IH}$ or $V_{IL}$								
	output voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH}$ or $V_{IL}$								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_1 = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±0.1	-	±1.0	-	±1.0	μA
I <sub>OZ</sub>	$\begin{array}{ll} \mbox{OFF-state} & \mbox{V}_{I} = \mbox{V}_{IH} \mbox{ or } \mbox{V}_{IL}; \\ \mbox{output current} & \mbox{V}_{O} = \mbox{V}_{CC} \mbox{ or } \mbox{GND}; \\ \mbox{V}_{CC} = 6.0 \mbox{ V} \end{array}$		-	-	±0.5	-	±5.0	-	±10.0	μA
I <sub>CC</sub>	supply current		-	-	8.0	-	80	-	160	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Мах	Min	Max	
74HCT4	094-Q100		I							
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V <sub>OH</sub> HIGH-level		$V_{I}$ = $V_{IH}$ or $V_{IL}$ ; $V_{CC}$ = 4.5 V								
	output voltage	I <sub>O</sub> = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 V$								
	output voltage	I <sub>O</sub> = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA	-	0.15	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	-	±1.0	-	±1.0	μA
I <sub>OZ</sub>	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL};$ $V_{O} = V_{CC} \text{ or } GND;$ $V_{CC} = 5.5 \text{ V}$	-	-	±0.5	-	±5.0	-	±10	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	8.0	-	80	-	160	μA
ΔI <sub>CC</sub>	additional supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} - 2.1 \ V;\\ \text{other inputs at } V_{CC} \ \text{or GND};\\ V_{CC} = 4.5 \ V \ \text{to} \ 5.5 \ V; \ I_{O} = 0 \ A \end{array}$								
		per input pin; STR input	-	100	360	-	450	-	490	μA
		per input pin; OE input	-	150	540	-	675	-	735	μA
		per input pin; CP input	-	150	540	-	675	-	735	μA
		per input pin; D input	-	40	144	-	180	-	196	μA
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

# **11. Dynamic characteristics**

## Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V);  $C_L$  = 50 pF unless otherwise specified; for test circuit see Fig. 10.

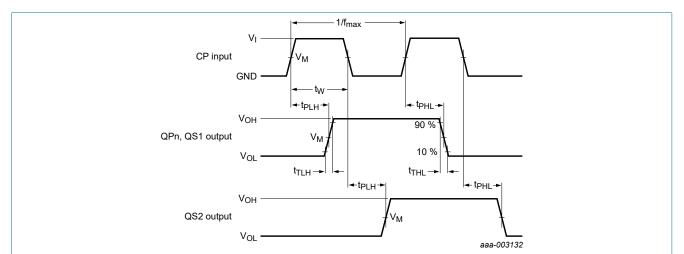
Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Мах	Min	Max	1
74HC40	94-Q100	1		1	1			1	1	
t <sub>pd</sub>	propagation	CP to QS1; see Fig. 6 [1]								
	delay	V <sub>CC</sub> = 2.0 V	-	50	150	-	190	-	225	ns
		V <sub>CC</sub> = 4.5 V	-	18	30	-	38	-	45	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	15	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	14	26	-	33	-	38	ns
		CP to QS2; see Fig. 6 [1]								
		V <sub>CC</sub> = 2.0 V	-	44	135	-	170	-	205	ns
		V <sub>CC</sub> = 4.5 V	-	16	27	-	34	-	41	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	13	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	13	23	-	29	-	35	ns
		CP to QPn; see Fig. 6 [1]								
		V <sub>CC</sub> = 2.0 V	-	63	195	-	245	-	295	ns
		V <sub>CC</sub> = 4.5 V	-	23	39	-	49	-	59	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	20	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	18	33	-	42	-	50	ns
		STR to QPn; see Fig. 7 [1]								
		V <sub>CC</sub> = 2.0 V	-	58	180	-	225	-	270	ns
		V <sub>CC</sub> = 4.5 V	-	21	36	-	45	-	54	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	18	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	17	31	-	38	-	46	ns
t <sub>en</sub>	enable time	OE to QPn; see Fig. 8 [1]								
		V <sub>CC</sub> = 2.0 V	-	55	175	-	220	-	265	ns
		V <sub>CC</sub> = 4.5 V	-	20	35	-	44	-	53	ns
		V <sub>CC</sub> = 6.0 V	-	16	30	-	37	-	45	ns
t <sub>dis</sub>	disable time	OE to QPn; see Fig. 8 [1]								
		V <sub>CC</sub> = 2.0 V	-	41	125	-	155	-	190	ns
		V <sub>CC</sub> = 4.5 V	-	15	25	-	31	-	38	ns
		V <sub>CC</sub> = 6.0 V	-	12	21	-	26	-	32	ns
t <sub>t</sub>	transition	QPn and QSn; see Fig. 6 [1]								1
	time	V <sub>CC</sub> = 2.0 V	-	19	75	-	95	-	110	ns
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	-	16	-	19	ns

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Мах	Min	Max	Min	Max	1
tw	pulse width	CP HIGH or LOW; see <u>Fig. 6</u>								
		V <sub>CC</sub> = 2.0 V	80	14	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	5	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	4	-	17	-	20	-	ns
		STR HIGH; see Fig. 7								
		V <sub>CC</sub> = 2.0 V	80	14	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	5	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	4	-	17	-	20	-	ns
t <sub>su</sub>	set-up time	D to CP; see Fig. 9								
		V <sub>CC</sub> = 2.0 V	50	14	-	65	-	75	-	ns
		V <sub>CC</sub> = 4.5 V	10	5	-	13	-	15	-	ns
		V <sub>CC</sub> = 6.0 V	9	4	-	11	-	13	-	ns
		CP to STR; see Fig. 7								
		V <sub>CC</sub> = 2.0 V	100	28	-	125	-	150	-	ns
		V <sub>CC</sub> = 4.5 V	20	10	-	25	-	30	-	ns
		V <sub>CC</sub> = 6.0 V	17	8	-	21	-	26	-	ns
t <sub>h</sub>	hold time	D to CP; see Fig. 9								
		V <sub>CC</sub> = 2.0 V	3	-6	-	3	-	3	-	ns
		V <sub>CC</sub> = 4.5 V	3	-2	-	3	-	3	-	ns
		V <sub>CC</sub> = 6.0 V	3	-2	-	3	-	3	-	ns
		CP to STR; see Fig. 7								
		V <sub>CC</sub> = 2.0 V	0	-14	-	0	-	0	-	ns
		V <sub>CC</sub> = 4.5 V	0	-5	-	0	-	0	-	ns
		V <sub>CC</sub> = 6.0 V	0	-4	-	0	-	0	-	ns
f <sub>max</sub>	maximum	CP; see Fig. 6								
	frequency	V <sub>CC</sub> = 2.0 V	6.0	28	-	4.8	-	4.0	-	MHz
		V <sub>CC</sub> = 4.5 V	30	87	-	24	-	20	-	MHz
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	95	-	-	-	-	-	MHz
		V <sub>CC</sub> = 6.0 V	35	103	-	28	-	24	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$C_L = 50 \text{ pF}; \text{ f} = 1 \text{ MHz};$ [2] V <sub>I</sub> = GND to V <sub>CC</sub>	-	83	-	-	-	-	-	pF

Symbol	Parameter	Conditions			25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
				Min	Тур	Max	Min	Max	Min	Max	-
74HCT4	094-Q100	1			1				1		1
t <sub>pd</sub>	propagation	CP to QS1; see Fig. 6	[1]								
	delay	V <sub>CC</sub> = 4.5 V		-	23	39	-	49	-	59	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF		-	19	-	-	-	-	-	ns
		CP to QS2; see Fig. 6	[1]								
		V <sub>CC</sub> = 4.5 V		-	21	36	-	45	-	54	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF		-	18	-	-	-	-	-	ns
		CP to QPn; see Fig. 6	[1]								
		V <sub>CC</sub> = 4.5 V		-	25	43	-	54	-	65	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF		-	21	-	-	-	-	-	ns
		STR to QPn; see Fig. 7	[1]								
		V <sub>CC</sub> = 4.5 V		-	22	39	-	49	-	59	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF		-	19	-	-	-	-	-	ns
t <sub>en</sub>	enable time	OE to QPn; see Fig. 8	[1]								-
		V <sub>CC</sub> = 4.5 V		-	20	35	-	44	-	53	ns
t <sub>dis</sub>	disable time	OE to QPn; see Fig. 8	[1]								
		V <sub>CC</sub> = 4.5 V		-	21	35	-	44	-	53	ns
t <sub>t</sub>	transition	QPn and QSn; see <u>Fig. 6</u>	[1]								
	time	V <sub>CC</sub> = 4.5 V		-	7	15	-	19	-	22	ns
t <sub>W</sub>	pulse width	CP HIGH or LOW; see <u>Fig. 6</u>									
		V <sub>CC</sub> = 4.5 V		16	7	-	20	-	24	-	ns
		STR HIGH; see Fig. 7									
		V <sub>CC</sub> = 4.5 V		16	5	-	20	-	24	-	ns
t <sub>su</sub>	set-up time	Dn to CP; see <u>Fig. 9</u>									
		V <sub>CC</sub> = 4.5 V		10	4	-	13	-	15	-	ns
		CP to STR; see Fig. 7									
		V <sub>CC</sub> = 4.5 V		20	9	-	25	-	30	-	ns
t <sub>h</sub>	hold time	Dn to CP; see <u>Fig. 9</u>									
		V <sub>CC</sub> = 4.5 V		4	0	-	4	-	4	-	ns
		CP to STR; see Fig. 7									
		V <sub>CC</sub> = 4.5 V		0	-4	-	0	-	0	-	ns
f <sub>max</sub>	maximum	CP; see <u>Fig. 6</u>									-
	frequency	V <sub>CC</sub> = 4.5 V		30	80	-	24	-	20	-	MHz
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF		-	86	-	-	-	-	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$C_{L} = 50 \text{ pF}; \text{ f} = 1 \text{ MHz}; $ $V_{I} = \text{GND to } V_{CC} - 1.5 \text{ V} $ [2]		-	92	-	-	-	-	-	pF

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ ;  $t_{en}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ ;  $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ ;  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ . [2]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).  $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;  $f_o$  = output frequency in MHz;  $C_L$  = output load capacitance in pF;  $V_{CC}$  = supply voltage in V; N = number of inputs switching;  $\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.



## 11.1. Waveforms and test circuits

Measurement points are given in Table 8.

V<sub>OL</sub> and V<sub>OH</sub> are typical voltage output levels that occur with the output load.

Fig. 6. Propagation delay input (CP) to output (QPn, QS1, QS2), output transition time, clock input (CP) pulse width and the maximum frequency (CP)

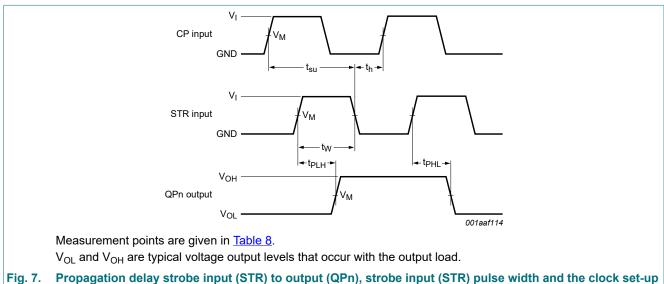
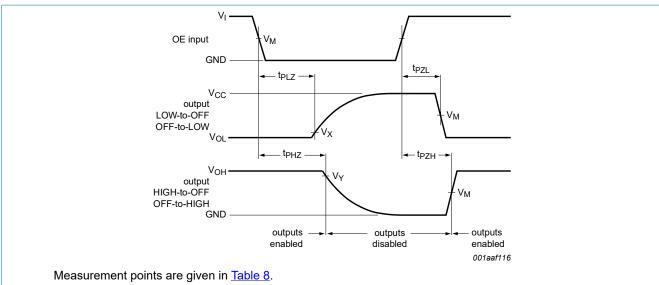
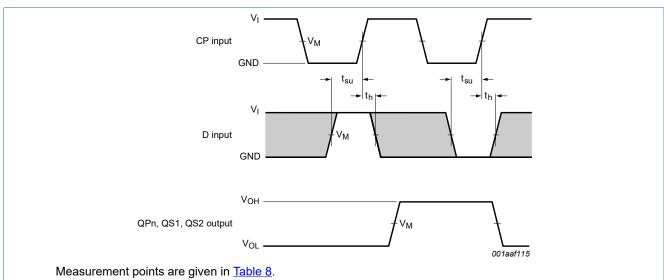


Fig. 7. Propagation delay strobe input (STR) to output (QPn), strobe i and hold times for strobe input



V<sub>OL</sub> and V<sub>OH</sub> are typical voltage output levels that occur with the output load.

## Fig. 8. Enable and disable times

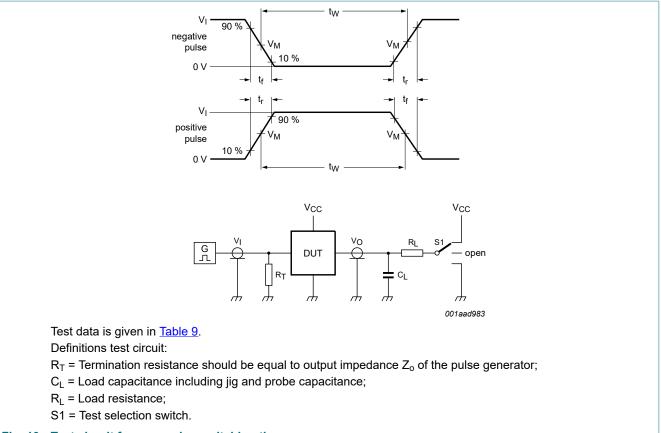


 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

Fig. 9	The data	input (D)	) to clock in	put (CP)	) set-up times an	d clock input (	CP) to	o data input	(D)	hold times
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#### Table 8. Measurement points

Туре	Input	Output							
	V <sub>M</sub>	V <sub>M</sub> V <sub>X</sub> V <sub>Y</sub>							
74HC4094-Q100	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>	0.1 × V <sub>OH</sub>	0.9 × V <sub>OH</sub>					
74HCT4094-Q100	1.3 V	1.3 V	0.1 × V <sub>OH</sub>	0.9 × V <sub>OH</sub>					

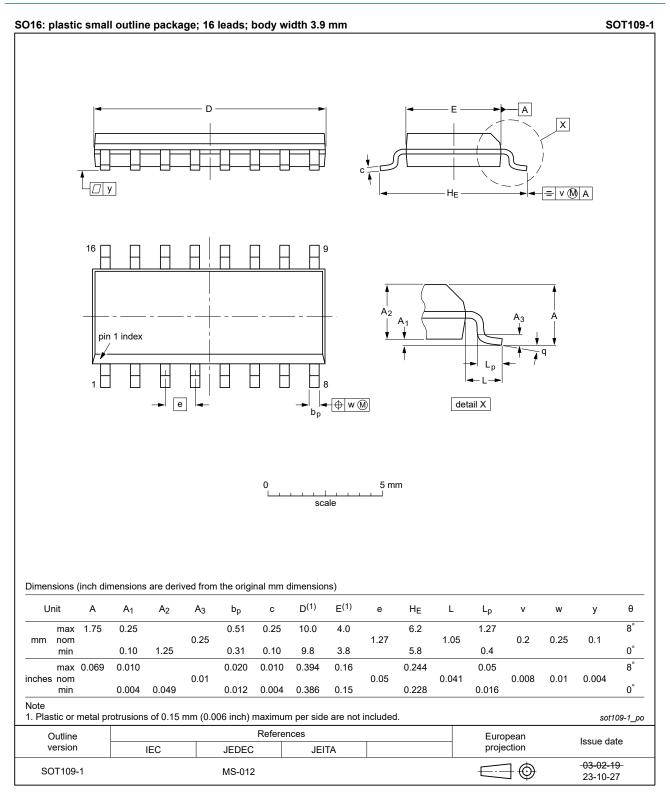


## Fig. 10. Test circuit for measuring switching times

## Table 9. Test data

Туре	Input		Load		S1 position		
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PHL</sub> , t <sub>PLH</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
74HC4094-Q100	V <sub>CC</sub>	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>
74HCT4094-Q100	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>

# 12. Package outline



## Fig. 11. Package outline SOT109-1 (SO16)

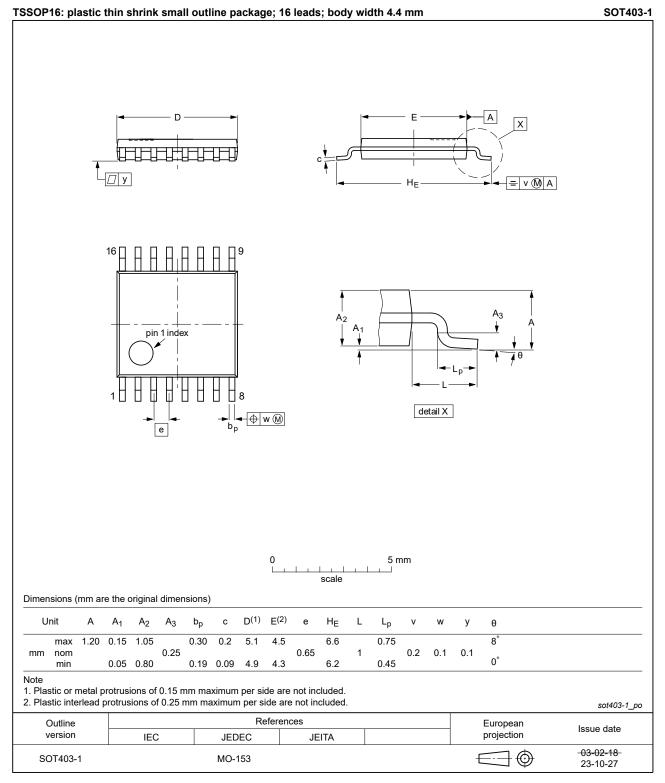


Fig. 12. Package outline SOT403-1 (TSSOP16)

# 13. Abbreviations

Table 10. Abbreviations				
Acronym	Description			
CDM	Charged Device Model			
CMOS	Complementary Metal Oxide Semiconductor			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
TTL	Transistor-Transistor Logic			

# 14. Revision history

## Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT4094_Q100 v.4	20240321	Product data sheet	-	74HC_HCT4094_Q100 v.3		
Modifications:	<ul> <li>Fig. 11, Fig. 12: Aligned SO and TSSOP package outline drawings to JEDEC MS-012 and MO-153.</li> <li>Section 2: ESD specification updated according to the latest JEDEC standard.</li> </ul>					
74HC_HCT4094_Q100 v.3	20211022	Product data sheet	-	74HC_HCT4094_Q100 v.2		
Modifications:	<ul> <li>Type numbers 74HC4094DB-Q100 and 74HCT4094DB-Q100 (SOT338-1/SSOP16) removed.</li> <li><u>Section 8</u>: Derating values for P<sub>tot</sub> total power dissipation updated.</li> </ul>					
74HC_HCT4094_Q100 v.2	20181114	Product data sheet	-	74HC_HCT4094_Q100 v.1		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Fig. 4 and Fig. 5 corrected.</li> </ul>					
74HC_HCT4094_Q100 v.1	20130130	Product data sheet	-	-		

# 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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